(a)
$$I_D = \frac{k_p'}{2} \cdot \frac{W}{L} \left[2(V_{SG} + V_T)V_{SD} - V_{SD}^2 \right]$$

= $\left(\frac{0.10}{2} \right) (15) \left[2(0.8 - 0.4)(0.25) - (0.25)^2 \right]$

$$I_D = 0.103 \text{ mA}$$
 $k'_- W$

(b)
$$I_D = \frac{k_p'}{2} \cdot \frac{W}{L} (V_{SG} + V_T)^2$$

= $\left(\frac{0.10}{2}\right) (15)(0.8 - 0.4)^2$
= $0.12 \,\text{mA}$

(c)
$$I_D = \frac{k_p'}{2} \cdot \frac{W}{L} (V_{SG} + V_T)^2$$

= $\left(\frac{0.10}{2}\right) (15) (1.2 - 0.4)^2$
= $0.48 \,\text{mA}$

(d) Same as (c), $I_D = 0.48 \text{ mA}$

2.

(a) Assume biased in saturation region

$$I_D = \frac{k_p'}{2} \cdot \frac{W}{L} (V_{SG} + V_T)^2$$
$$0.10 = \left(\frac{0.12}{2}\right) (20)(0 + V_T)^2$$

$$\Rightarrow V_T = +0.289 \text{ V}$$

Note:
$$V_{SD} = 1.0 \text{ V} > V_{SG} + V_T = 0 + 0.289 \text{ V}$$

So the transistor is biased in the saturation region.

(b)
$$I_D = \left(\frac{0.12}{2}\right)(20)(0.4 + 0.289)^2$$

= 0.570 mA

(c)
$$I_D = \left(\frac{0.12}{2}\right)(20)[2(0.6 + 0.289)(0.15) - (0.15)^2]$$

OI

$$I_n = 0.293 \text{ mA}$$

(a)
$$n^+$$
 poly-to-p-type $\Rightarrow \phi_{ms} = -1.0 \text{ V}$

$$\phi_{fb} = (0.0259) \ln \left(\frac{10^{15}}{1.5 \times 10^{10}} \right) = 0.288 \text{ V}$$
also
$$x_{dT} = \left[\frac{4 \in_{s} \phi_{fb}}{eN_{a}} \right]^{1/2}$$

$$= \left[\frac{4(11.7)(8.85 \times 10^{-14})(0.288)}{(1.6 \times 10^{-19})(10^{15})} \right]^{1/2}$$
or
$$x_{dT} = 0.863 \times 10^{-4} \text{ cm}$$
Now
$$|Q'_{SD}(\text{max})| = (1.6 \times 10^{-19})(10^{15})(0.863 \times 10^{-4})$$
or
$$|Q'_{SD}(\text{max})| = 1.38 \times 10^{-8} \text{ C/cm}^2$$
Also

 $C_{ox} = \frac{\epsilon_{ox}}{t} = \frac{(3.9)(8.85 \times 10^{-14})}{400 \times 10^{-8}}$

$$C_{ox} = 8.63 \times 10^{-8} \text{ F/cm}^2$$
We find
$$Q'_{55} = (1.6 \times 10^{-19})(5 \times 10^{10}) = 8 \times 10^{-9} \text{ C/cm}^2$$
Then
$$V_T = \frac{|Q'_{5D}|(\text{max})| - Q'_{55}|}{C_{ox}} + \phi_{mx} + 2\phi_{fb}$$

$$= \left(\frac{1.38 \times 10^{-8} - 8 \times 10^{-9}}{8.63 \times 10^{-8}}\right) - 1.0 + 2(0.288)$$
or
$$V_T = -0.357 \text{ V}$$
(b) For NMOS, apply V_{5B} and V_T shifts in a positive direction, so for $V_T = 0$, we want
$$\Delta V_T = +0.357 \text{ V}.$$
So
$$\Delta V_T = \frac{\sqrt{2e \in_{\mathcal{I}} N_a}}{C_{ox}} \left[\sqrt{2\phi_{fb} + V_{5B}} - \sqrt{2\phi_{fb}}\right]$$
or
$$+0.357 = \frac{\sqrt{2(1.6 \times 10^{-19})(11.7)(8.85 \times 10^{-14})(10^{15})}}{8.63 \times 10^{-8}} \times \left[\sqrt{2(0.288) + V_{5B}} - \sqrt{2(0.288)}\right]$$
or
$$0.357 = 0.211 \left[\sqrt{0.576 + V_{5B}} - \sqrt{0.576}\right]$$
which yields
$$V_{5B} = 5.43 \text{ V}$$

4.

01

(a)
$$g_{m} = \frac{W\mu_{n}C_{ox}}{L}(V_{GS} - V_{T})$$

$$= \frac{W\mu_{n} \in_{ox}}{Lt_{ox}}(V_{GS} - V_{T})$$
 or
$$r_{s} = 0.198 \text{ k} \Omega$$
$$= \frac{(10)(400)(3.9)(8.85 \times 10^{-14})}{475 \times 10^{-8}} (5 - 0.65)$$
 (b) For $V_{GS} = 3 \text{ V}$, $g_{m} = 0.683 \text{ mS}$ Then

 $g_m = 1.26 \,\text{mS}$

$$g'_m = \frac{g_m}{1 + g_m r_z} \Rightarrow \frac{g'_m}{g_m} = 0.8 = \frac{1}{1 + g_m r_z}$$
which yields

$$r_s = \frac{1}{g_m} \left(\frac{1}{0.8} - 1 \right) = \frac{1}{1.26} \left(\frac{1}{0.8} - 1 \right)$$

$$r_{*} = 0.198 \,\mathrm{k}\,\Omega$$

$$g'_m = \frac{0.683}{1 + (0.683)(0.198)} = 0.602 \text{ mS}$$

$$\frac{g_m'}{g_m} = \frac{0.602}{0.683} = 0.88$$

which is a 12% reduction.

(a)
$$I_D = 10^{-15} \exp\left(\frac{V_{GS}}{(2.1)V_t}\right)$$

For $V_{GS} = 0.5 \,\text{V}$,

$$I_D = 10^{-15} \exp \left[\frac{0.5}{(2.1)(0.0259)} \right] \Rightarrow$$

$$I_D = 9.83 \times 10^{-12} \,\mathrm{A}$$

For
$$V_{GS} = 0.7 \text{ V}$$
,

$$I_D = 3.88 \times 10^{-10} \text{ A}$$

For
$$V_{GS} = 0.9 \text{ V}$$
,

$$I_D = 1.54 \times 10^{-8} \,\mathrm{A}$$

Then the total current is:

$$I_T = I_D \left(10^6 \right)$$

For
$$V_{GS} = 0.5 \,\text{V}$$
, $I_T = 9.83 \,\mu \,\text{A}$

For
$$V_{GS} = 0.7 \text{ V}$$
, $I_T = 0.388 \text{ mA}$

For
$$V_{GS} = 0.9 \text{ V}$$
, $I_T = 15.4 \text{ mA}$

(b)

Power:
$$P = I_T \cdot V_{DD}$$

Then

For
$$V_{GS} = 0.5 \text{ V}$$
, $P = 49.2 \mu \text{ W}$

For
$$V_{GS} = 0.7 \text{ V}$$
, $P = 1.94 \text{ mW}$

For
$$V_{GS} = 0.9 \text{ V}, P = 77 \text{ mW}$$

$$C_{ox} = \frac{\epsilon_{ox}}{t_{ox}} = \frac{(3.9)(8.85 \times 10^{-14})}{120 \times 10^{-8}}$$

$$= 2.876 \times 10^{-7} \text{ F/cm}^{2}$$

$$V_{FB} = \phi_{ms} - \frac{Q'_{ss}}{C_{ox}}$$

$$= -0.5 - \frac{(4 \times 10^{10})(1.6 \times 10^{-19})}{2.876 \times 10^{-7}}$$

$$V_{FB} = -0.5223 \text{ V}$$
Now
$$V_{T} = \frac{|Q'_{SD}(\text{max})|}{C_{ox}} + V_{FB} + 2\phi_{fp}$$
We find
$$\phi_{fp} = (0.0259) \ln \left(\frac{4 \times 10^{16}}{1.5 \times 10^{10}}\right) = 0.3832 \text{ V}$$

$$X_{aT} = \left[\frac{4(11.7)(8.85 \times 10^{-14})(0.3832)}{(1.6 \times 10^{-19})(4 \times 10^{16})}\right]^{1/2}$$

$$= 1.575 \times 10^{-5} \text{ cm}$$

$$|Q'_{SD}(\text{max})|$$

$$= (1.6 \times 10^{-19})(4 \times 10^{16})(1.575 \times 10^{-5})$$

$$= 1.008 \times 10^{-7} \text{ C/cm}^{2}$$
So
$$V_{T} = \frac{1.008 \times 10^{-7}}{2.876 \times 10^{-7}} - 0.5223 + 2(0.3832)$$

$$= 0.595 \text{ V}$$

$$V_{DS}(sat) = V_{GS} - V_{T} = 1.25 - 0.595 = 0.655 \text{ V}$$

$$\sqrt{\frac{2 \,\epsilon_{_{S}}}{eN_{_{B}}}} = \sqrt{\frac{2(11.7)(8.85 \times 10^{-14})}{(1.6 \times 10^{-19})(4 \times 10^{16})}}$$

$$= 1.799 \times 10^{-5} \, \text{cm/V}^{1/2}$$
(a) $\Delta L = \sqrt{\frac{2 \,\epsilon_{_{S}}}{eN_{_{B}}}} \left[\sqrt{\phi_{_{B}} + V_{_{DS}}(sat)} + \Delta V_{_{DS}} - \sqrt{\phi_{_{B}} + V_{_{DS}}(sat)} \right]$

$$(i) \Delta L = (1.799 \times 10^{-5})$$

$$\times \left[\sqrt{0.3832 + 0.655 + 1} - \sqrt{0.3832 + 0.655} \right]$$

$$\Delta L = 7.35 \times 10^{-6} \, \text{cm} = 0.0735 \, \mu \, \text{m}$$
(ii) $\Delta L = (1.799 \times 10^{-5})$

$$\times \left[\sqrt{0.3832 + 0.655 + 2} - \sqrt{0.3832 + 0.655} \right]$$

$$\Delta L = 1.303 \times 10^{-5} \, \text{cm} = 0.1303 \, \mu \, \text{m}$$
(iii) $\Delta L = (1.799 \times 10^{-5})$

$$\times \left[\sqrt{0.3832 + 0.655 + 4} - \sqrt{0.3832 + 0.655} \right]$$

$$\Delta L = 2.205 \times 10^{-5} \, \text{cm} = 0.2205 \, \mu \, \text{m}$$
(b) $\frac{\Delta L}{L} = 0.12 = \frac{0.2205}{L}$

(i)
$$I_D = \frac{k'_n}{2} \cdot \frac{W}{L} (V_{GS} - V_T)^2$$

= $\left(\frac{0.075}{2}\right) (10) (0.8 - 0.35)^2$

$$= 0.07594 \,\mathrm{mA} = 75.94 \,\mu\,\mathrm{A}$$

(ii)
$$I'_D = I_D (1 + \lambda V_{DS})$$

= $(75.9375)[1 + (0.02)(1.5)]$
= $78.22 \mu \text{ A}$

(iii)
$$r_o = \frac{1}{\lambda I_D} = \frac{1}{(0.02)(75.94)}$$

= 0.658 M Ω = 658 k Ω

(i)
$$I_D = \left(\frac{0.075}{2}\right) (10) (1.25 - 0.35)^2$$

$$= 0.30375 \, \text{mA}$$

= 0.30375 mA
(ii)
$$I'_D = (0.30375)[1 + (0.02)(1.5)]$$

= 0.3129 mA

(iii)
$$r_o = \frac{1}{(0.02)(0.30375)} = 165 \text{ k} \Omega$$

8.

(i)
$$I_D(\max) = \frac{k_n'}{2} \cdot \frac{W}{L} \cdot (V_{GS} - V_T)^2$$

= $\left(\frac{0.15}{2}\right) \left(\frac{6}{1.2}\right) (3 - 0.45)^2$

(ii) Scaled device:

$$V_D = V_{GS} = k(3) = (0.65)(3) = 1.95 \text{ V}$$

 $k'_n = \left(\frac{0.15}{k}\right) = \left(\frac{0.15}{0.65}\right) = 0.2308 \text{ mA/V}^2$
 $L = k(1.2) = (0.65)(1.2) = 0.78 \mu \text{ m}$
 $W = k(6) = (0.65)(6) = 3.90 \mu \text{ m}$

Then

$$I_D(\text{max}) = \left(\frac{0.2308}{2}\right) \left(\frac{3.9}{0.78}\right) (1.95 - 0.45)^2$$

$$=1.298 \, \text{mA}$$

(b) (i)
$$P(\text{max}) = I_D(\text{max})V_D = (2.438)(3)$$

= 7.314 mW

(ii)
$$P(max) = (1.298)(1.95)$$

= 2.531 mW

$$C_{ox} = \frac{(3.9)(8.85 \times 10^{-14})}{80 \times 10^{-8}}$$

$$= 4.314 \times 10^{-7} \text{ F/cm}^2$$

$$\phi_{fp} = (0.0259) \ln \left(\frac{2 \times 10^{16}}{1.5 \times 10^{10}} \right) = 0.3653 \text{ V}$$

$$x_{dT} = \left[\frac{4(11.7)(8.85 \times 10^{-14})(0.3653)}{(1.6 \times 10^{-19})(2 \times 10^{16})} \right]^{1/2}$$

$$= 2.174 \times 10^{-5} \text{ cm}$$

$$\Delta V_T = -\frac{(1.6 \times 10^{-19})(2 \times 10^{16})(2.174 \times 10^{-5})}{4.314 \times 10^{-7}}$$

$$\times \left[\frac{0.30}{0.70} \left(\sqrt{1 + \frac{2(0.2174)}{0.30}} - 1 \right) \right]$$

$$\Delta V_T = -0.0391 \text{ V}$$

$$V_T = V_{TO} + \Delta V_T$$

$$0.35 = V_{TO} - 0.0391$$

$$\Rightarrow V_{TO} = 0.389 \text{ V}$$